A Precision Transconductance for Electrical Impedance Tomography Using CMOS Technology

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ABSTRACT: Current Drivers are suitable for bioimpedance measurements applications. The CMOS current driver circuits are portable for high resolution, high frequency image system. Current driver are require accurate output current value. This current driver circuits are introduced based on a transconductance and provide accurate current output. This circuit design uses multithreshold CMOS technology (MTCMOS) and negative feedback. The circuit was fabricated in a 0.22µm MTCMOS process technology. It operates at 5V power supply and it can deliver the output current 5mA.

KEYWORDS: CMOS current driver; Transconductance; bioimpedance; Electrical impedance tomography (EIT); Multithreshold CMOS technology.

I. INTRODUCTION

ELECTRICAL IMPEDANCE TOMOGRAPHY (EIT) is a new medical imaging technique. These system offers a non-invasive, low cost medical image approach [1][16]. Most bioimpedance measurement techniques are particular interest in EIT. Current patterns are applying to the body surface through electrodes and measure the resulting voltage. A complete set of impedance measurement may be reconstructed into tomographical image [12]. Some EIT system use multifrequency to get better differentiation between normal and abnormal tissue within the same organ [2][13]. Current driver are the fundamental circuit in EIT system. These circuits are suitable for bioimpedance application. Current driver is used to control the circuit such as high power transistor. They are usually used to regulate the current flowing through a circuit or are used to control the other factors such as other component, some device in the circuits. These circuits to provide accurate output current to the tissue load [2][9]. Current driver circuits have three stages there are preamplifier, transconductance, voltage buffer. This circuit design uses differential amplifier and negative feedback. Here using multifrequency operation in transconductance stage so it consumes more power. The main limitation of this current driver is the upper frequency operation limits by the delay present at high frequency and it consumes more power [1][14].

Considerable effort has been made to reduce or even eliminate this limitation, first to develop a current driver circuit uses negative feedback and multithreshold CMOS technology. This paper presents a current driver based on transconductance stage. The second objective is to modify the transconductance stage using MTCMOS. To optimizes power consumption and it provides maximum output current accuracy. This paper is an expansion of [1] and presents the complete design and simulation results of current driver in 0.22-µm Multithreshold CMOS technology. This paper organized as follows. Section II outlines the system architecture and operation of current driver. Section III describes the circuit design. Section IV present simulation results of current driver. The concluding remarks of Section V complete the paper.

II. RELATED WORK

Andres Demosthenous, Peter J. Langlos proposed the paper “A Sinusoidal Current Driver with Extended Frequency Range and Multifrequency Operation for Bioimpedance Application” describes about the alternative sinusoidal current
driver design uses nonlinear feedback and it provides outputs with low phase error. This circuit more suitable for high
frequency integrated circuit applications. The drawback of this system is multifrequency currents can generated only
each individual frequency phase is corrected [2][17].

Detection System” describes about the mobile EIT IC is proposed for early breast cancer detection personally at
home. This system design by Differential sinusoidal current source and it support three operating mode gain scanning,
contact impedance monitoring, and EIT modes for the clear EIT image. The main drawback of this system is achieve
high output impedance it suffers from a high common mode voltage error appearing across the load [3].

Marco Guermandi, R cardu, R Guerrieri proposed the paper “Active Electrode IC for EEG& EIT with continuous
monitoring of contact impedance” describes about the IC is designed to acquire EEG and EIT signals at the same
time so as to have the best possible integration between the two techniques. This overcomes the common limitations
associated with using two separate systems for EEG and EIT. This system electrode able to program at any time and it
improve the output signal quality. The main drawback of this system is suffer from low spatial resolution
[4][18]. Gustavo sato dos santos, Simon Arridge, David Holder proposed the “Multifrequency Electrical Impedance
Tomography using Spectral Constraints” describes about the Multifrequency electrical impedance tomography (MFEIT)
the dependence of tissue impedance on frequency to recover an image of conductivity. This system provides emergency
diagnosis of pathologies such as acute stroke, brain injury and breast cancer. The main drawback is conductivity image
is not possible [5][20].

Sntos.S.A, Leonhardt S proposed the “Simulation of a Current Source with a Cole-Cole for Multifrequency
EIT” describes the accurate current source is one of the keys in the hardware of Electrical impedance Tomography
systems. This system design uses improve Howland current source and it provides a constant and stable output
current. Limitations appear at high frequencies operations[9]. Aaron S, Tucker, Robert M, Fox, Rosalind J, Sadleir
proposed the “Biocompatible, high precision, wideband, Improved howland current source with Lead-leg
compensation” describes the bioelectrical circuit is deliver precise electrical currents. This paper is improved current
driver based on a pair of balanced operational transconductance amplifiers using a negative feedback loop. The
drawback of this system is output impedance of the Howland is a critical figure of merit that limits the precision of the
delivered current when the load changes[10].

III. SYSTEM ARCHITECTURE

Figure 1 shows the block diagram of the current driver. It consists of three major building blocks; preamplifier,
transconductance, voltage buffer. Current driver design by using negative feedback and MTCMOS. The use of negative
feedback therefore reduces input source error and circuit should be stable and also it enhances the circuit output
current. Multithreshold CMOS uses in the transconductance stage it optimize power consumption.
A. Preamplifier

The preamplifier circuit is used to improve the small electric signal strength. These circuits are designed by cascode current mirror [1]. It is used to boost the signal strength to drive the cable to the main circuit without significant degrading the signal to noise (SNR).

B. Transconductance

The transconductance circuit is designed based on multithreshold CMOS technology. The use of MTCMOS is to optimize the power consumption. These circuits act as a port to transmit input signal from input source to output side without voltage drop. Their purpose is to enhance output current and signal gain value.

C. Voltage Buffer

The voltage buffer circuit design by using intersection of inverter. These circuits are used to measure the output voltage. Voltage buffer output is fed into preamplifier negative input terminal it forms the negative feedback path. This path is optimizing accruing noise in this circuit.

IV. CIRCUIT DESIGN

A. Preamplifier

Figure 2 shows the schematic diagram of the preamplifier. These circuits are often placed close to the input source to reduce the effect of noise and interference.

Input voltage source (5v) applied to the M2 transistor. These circuits designed by cascode current mirror. Biases current are applied to the all transistors. Voltage source are applied to the v1, v2 terminals. Clock signal are applied to the M6, M13 transistors. These signal is control the power supply of the whole current driver circuits. Bais are the constant current source. Here 5mA constant current source is applied to the M2, M3 transistors. Current mirror form by transistor M1-M4. Output of these circuits is fed into input terminal of the transconductance circuit. Here 14 transistors are used. Common mode voltage error appears in this circuit. If the error is not rejected, it appears as an error at these circuit output. This error was negligible based on high common mode rejection ratio (CMRR) of this circuit. CMRR is reject the unwanted input signal. These circuits provide the constant output and enhance the gain value.
B. Transconductance

Figure 3 shows the schematic diagram of the transconductance. Input current source is applied to the M15-M17 of the transistors in this circuit. In this transconductance stage is an important part of the current driver system. Preamplifier output voltage is fed into transconductance input v2 terminal. Operation of this circuit is to transmit the input source from input terminal to output source without any signal drop. In conventional circuits, consume more power in this stage. So we use multithreshold CMOS technology in proposed current driver circuits. This technology which has transistors with multiple threshold voltage optimize power and delay.

Creating devices with multiple threshold voltage is to apply different bias voltage to the base terminal of the transistor. In this circuit apply different bias voltage to the transistors. These circuits have a large number of transistors in a current driver, the greater gain it is capable of delivering which all other factors constant. It has directly control the current through the circuit. Their purpose is to produce high output impedance, current maintain at constant and enhance the gain. Current driver require high output impedance and stable current to the output. These circuit used to regulate and set the voltage to produce constant output.
C. Voltage buffer

Figure 4 shows the schematic diagram of the voltage buffer. This circuit design by using CMOS inverter. These circuit uses four inverters. Inverter are (M1-M2)(M3-M4) (M5-M6)(M7-M8). Inveter1,2 connected in serial and 3,4 also connected in serial.

A voltage buffer is used to transfer a voltage from a first circuit, having a high output impedance level, to a second circuit with a low input impedance level. The interposed buffer amplifier prevents the second circuit from loading the first circuit unacceptably and interfering with its desired operation.

Transconductance M14,M15 transistor input fed into voltage buffer(M1-M2)(M3-M4) inverter input terminals. These circuit operates with very low power loss and at relatively high speed. Output voltage are measured by this circuit. Their purpose is provides short transmission time and low power consumption.

V. MEASUREMENT AND RESULT

The proposed current driver with MTCMOS technology show in Figure 5 was designed in 0.22-µm CMOS technology. From the experimental results shows in table 1, the input voltage of conventional is 18V, then the input voltage of proposed current driver is 5V and output voltage is 5V.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Conventional system [1]</th>
<th>Proposed system</th>
</tr>
</thead>
<tbody>
<tr>
<td>Technology</td>
<td>0.6µm CMOS Technology</td>
<td>0.22µm CMOS Technology</td>
</tr>
<tr>
<td>Architecture</td>
<td>High voltage CMOS Technology and Negative feedback</td>
<td>Multithreshold CMOS Technology and Negative feedback</td>
</tr>
<tr>
<td>Maximum output current</td>
<td>5mA</td>
<td>~5mA</td>
</tr>
<tr>
<td>Supply voltage</td>
<td>18V</td>
<td>5V</td>
</tr>
</tbody>
</table>

Table 1. comparison table between conventional and proposed system

The maximum output current of conventional is 5mA, then the proposed current driver is 5mA. Proposed current driver reduce the power consumption is 20nW compare with conventional system.
VI. CONCLUSION

In this paper, we designed and simulated the current driver with Multithreshold CMOS to achieve accurate output current and low power consumption. We concentrated on the output current accuracy is increase and reduces power consumption compare with a conventional system. For this design of CMOS current driver in CMOS design methodology we used Tanner EDA 15.11 simulation tool.

REFERENCES


